Low-power buffer/line driver; 3-state Rev. 6 — 15 August 2012

Product data sheet

General description 1.

The 74AUP1G125 provides a single non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (OE). A HIGH level at pin OE causes the output to assume a high-impedance OFF-state. This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input OE) is HIGH.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

Features and benefits 2.

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



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Ordering information 3.

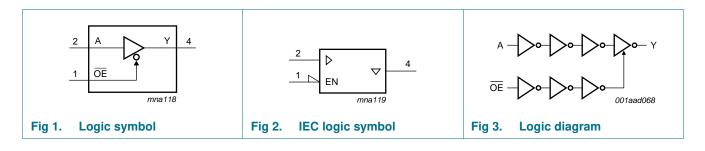
Table 1. Ordering	g information							
Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G125GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G125GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74AUP1G125GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74AUP1G125GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AUP1G125GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74AUP1G125GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

Marking 4.

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1G125GW	рМ
74AUP1G125GM	рМ
74AUP1G125GF	рМ
74AUP1G125GN	рМ
74AUP1G125GS	рМ
74AUP1G125GX	рМ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

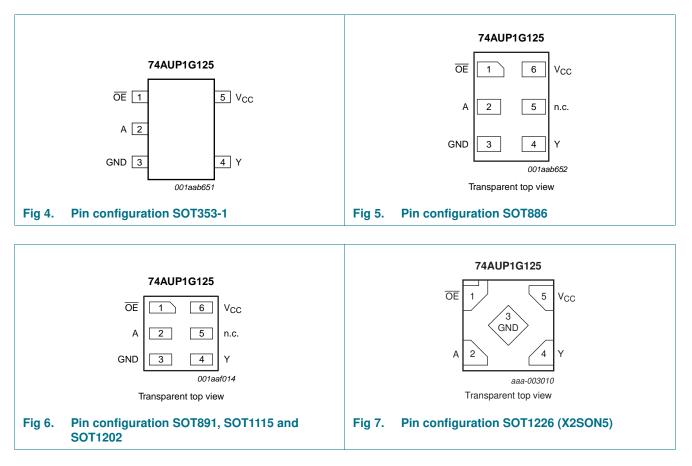
Functional diagram 5.



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Pinning information 6.

6.1 Pinning



6.2 Pin description

Table 3.	Pin des	scription		
Symbol		Pin		Description
		TSSOP5 and X2SON5	XSON6	
OE		1	1	output enable input
A		2	2	data input
GND		3	3	ground (0 V)
Y		4	4	data output
n.c.		-	5	not connected
V _{CC}		5	6	supply voltage

7. Functional description

Input OE		Output
OE	Α	Y
L	L	L
L	Н	Н
Н	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = Don't care;

Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode	<u>[1]</u> –0.5	$V_{CC} + 0.5$	V
		Power-down mode	<u>[1]</u> –0.5	+4.6	V
l _O	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[2]	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
 For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6.	Recommended operating conditi	ons			
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 \text{ V} \text{ to } 3.6 \text{ V}$	0	200	ns/V

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 V \text{ to } 3.6 V$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
l _l	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μA
oz	OFF-state output current		-	-	±0.1	μA
OFF	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
∆l _{OFF}	additional power-off leakage current	V_1 or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I}=GND \text{ or } V_{CC}; \ I_{O}=0 \ A; \\ V_{CC}=0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	0.5	μA

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Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
∆l _{CC}	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1] -	-	40	μA
		$\label{eq:VCC} \overline{\text{OE}} \text{ input; } V_{\text{I}} = V_{\text{CC}} - 0.6 \text{ V; } I_{\text{O}} = 0 \text{ A;} \\ V_{\text{CC}} = 3.3 \text{ V}$	<u>[1]</u> -	-	110	μA
		all inputs; V _I = GND to 3.6 V; \overline{OE} = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	[2] -	-	1	μA
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.9	-	pF
Co	output capacitance					
	output enabled	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
	output disabled	V_{CC} = 0 V to 3.6 V; V_O = GND or V_{CC}	-	1.5	-	pF
T _{amb} = –	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	۷
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	۷
V _{OH}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	٧
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	٧
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	٧
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	٧
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	٧
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	٧
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	٧
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
1	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
oz	OFF-state output current		-	-	±0.5	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
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roduct d	ata sheet	Rev. 6 — 15 August 2012				6 of 2

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
∆I _{OFF}	additional power-off leakage current	$ V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; $		-	-	±0.6	μA
CC	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$		-	-	0.9	μA
Alcc	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1]	-	-	50	μA
		$\overline{\text{OE}}$ input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	120	μA
		$\frac{\text{all inputs; V}_{\text{I}} = \text{GND to } 3.6 \text{ V;}}{\text{OE}} = \text{V}_{\text{CC}}; \text{V}_{\text{CC}} = 0.8 \text{ V to } 3.6 \text{ V}}$	<u>[2]</u>	-	-	1	μA
amb = -	40 °C to +125 °C						
/ _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$		$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V		$0.70 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.0	-	-	V
/ _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$		-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V		-	-	$0.30\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	-	0.9	V
/ _{ОН} Н	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I_O = –20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V		$V_{CC}-0.11$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$		$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$		0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$		1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.30	-	-	V
/ _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I_O = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V		-	-	0.11	V
		$I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$		-	-	$0.33 \times V_{CC}$	V
		$I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$		-	-	0.41	V
		$I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$		-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	0.50	V
	input leakage current	$V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V		-	-	±0.75	μA
OZ	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 V \text{ to } 3.6 V; \\ V_{CC} = 0 V \text{ to } 3.6 V \end{array}$		-	-	±0.75	μA
OFF	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.75	μA

Table 7. Static characteristics ...continued

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Low-power buffer/line driver; 3-state

At recom	mended operating conditions	s; voltages are referenced to GND (grour	nd = 0 V).			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI_{OFF}	additional power-off leakage current	$ V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V}; \\ V_{CC} = 0 \text{ V to } 0.2 \text{ V} $	-	-	±0.75	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	1.4	μΑ
ΔI_{CC}	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> _	-	75	μA
		\overline{OE} input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1] -	-	180	μA
		all inputs; $V_1 = GND$ to 3.6 V; $\overline{OE} = V_{CC}$; $V_{CC} = 0.8$ V to 3.6 V	[2] _	-	1	μA

Table 7. Static characteristics ... continued

[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

[2] To show I_{CC} remains very low when the input-disable feature is enabled.

11. Dynamic characteristics

Table 8. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
T _{amb} = 25	°C; C _L = 5 pF						
t _{pd}	propagation delay	A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	20.6	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.8	5.5	10.5	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.2	3.9	6.1	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.9	3.2	4.8	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.6	2.6	3.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.4	2.4	3.1	ns
t _{en}	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	69.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	6.1	11.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	4.2	6.6	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.1	3.4	5.1	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	2.6	3.7	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.7	2.4	3.1	ns
t _{dis}	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	14.3	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	4.3	6.5	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	3.2	4.4	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		2.0	3.0	4.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.4	2.2	2.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.7	2.5	3.2	ns

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Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
Г _{ать} = 25	°C; C _L = 10 pF						
pd	propagation delay	A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	24.0	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.2	6.4	12.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	4.5	7.3	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.9	3.8	5.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	3.2	4.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.8	3.0	3.8	ns
en	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	73.7	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.6	6.9	13.5	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.3	4.8	7.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.0	3.9	5.8	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.8	3.2	4.3	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.0	3.9	ns
dis	disable time	OE to Y; see Figure 9	[4]				
		V _{CC} = 0.8 V		-	32.7	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.4	5.4	7.9	ns
		V _{CC} = 1.4 V to 1.6 V		2.2	4.1	5.5	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	4.2	5.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	3.0	3.8	ns
		V _{CC} = 3.0 V to 3.6 V		2.1	3.8	4.8	ns
amb = 25	°C; C _L = 15 pF						
pd	propagation delay	A to Y; see Figure 8	[2]				
1		$V_{CC} = 0.8 V$		-	27.4	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.6	7.2	14.1	ns
		V _{CC} = 1.4 V to 1.6 V		3.0	5.1	8.1	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	4.3	6.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	3.7	4.9	ns
		V _{CC} = 3.0 V to 3.6 V		2.0	3.5	4.4	ns
en	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	77.5	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.0	7.7	15.2	ns
		V _{CC} = 1.4 V to 1.6 V		3.0	5.3	8.4	ns
		V _{CC} = 1.65 V to 1.95 V		2.3	4.4	6.5	ns
		V _{CC} = 2.3 V to 2.7 V		2.1	3.6	5.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.0	3.5	4.5	ns

Table 8. Dynamic characteristics ... continued

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
t _{dis}	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	60.8	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.3	6.5	9.2	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	5.0	6.5	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		3.0	5.3	6.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	3.8	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.9	5.0	6.2	ns
T _{amb} = 25	°C; C _L = 30 pF						
t _{pd} propagation delay		A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	37.4	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	9.5	19.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.0	6.7	10.8	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.9	5.6	8.4	ns
		V_{CC} = 2.3 V to 2.7 V		2.7	4.8	6.3	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.7	4.6	5.8	ns
t _{en}	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	88.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		5.2	9.9	19.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.0	6.8	10.8	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		3.0	5.6	8.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.7	4.8	6.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.7	4.6	6.0	ns
t _{dis}	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	49.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		6.0	9.9	13.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.4	7.7	9.6	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		5.1	8.7	11.1	ns
		V_{CC} = 2.3 V to 2.7 V		3.6	6.2	7.4	ns
		V _{CC} = 3.0 V to 3.6 V		5.2	8.7	10.5	ns

Table 8. Dynamic characteristics ... continued

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
T _{amb} = 25	5 °C						
C _{PD} power dissipation capacitance		f = 1 MHz; V_I = GND to V_{CC}	[5]				
		output enabled					
	$V_{CC} = 0.8 V$		-	2.7	-	pF	
		V _{CC} = 1.1 V to 1.3 V		-	2.8	-	pF
		V _{CC} = 1.4 V to 1.6 V		-	2.9	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	3.0	-	pF
		V_{CC} = 2.3 V to 2.7 V		-	3.6	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	4.2	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	4.2		-

Dynamic characteristics ... continued Table 8.

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[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$ f_i = input frequency in MHz; $f_o = output frequency in MHz;$ C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Table 9. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to	Unit	
				Min	Max	Min	Max	
C _L = 5 pF								
t _{pd}	propagation delay	A to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	11.7	2.5	12.9	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.0	7.3	2.0	8.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.7	6.1	1.7	6.7	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.4	4.3	1.4	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.2	3.9	1.2	4.4	ns
t _{en}	enable time	OE to Y; see Figure 9	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.9	13.9	2.9	15.4	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.3	7.7	2.3	8.3	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.0	6.2	2.0	6.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	4.5	1.7	5.0	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.5	1.7	3.9	ns

Low-power buffer/line driver; 3-state

Symbol Parameter		Conditions		–40 °C to +85 °C		-40 °C to +125 °C		Unit	
				Min	Max	Min	Max		
dis	disable time	OE to Y; see Figure 9	[3]						
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		2.7	7.3	2.7	8.2	ns	
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	5.1	2.1	5.7	ns	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.0	5.0	2.0	5.7	ns	
		V_{CC} = 2.3 V to 2.7 V		1.4	3.3	1.4	4.1	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.4	1.7	3.9	ns	
C _L = 10 p	F								
pd	propagation delay	A to Y; see Figure 8	[1]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.0	13.8	3.0	15.2	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		1.9	8.5	1.9	9.4	ns	
		V _{CC} = 1.65 V to 1.95 V		1.7	6.8	1.7	7.6	ns	
		V_{CC} = 2.3 V to 2.7 V		1.6	5.3	1.6	5.9	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.6	4.6	1.6	5.2	ns	
en	enable time	OE to Y; see Figure 9	[2]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.4	15.8	3.4	17.5	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.2	8.6	2.2	9.4	ns	
		V _{CC} = 1.65 V to 1.95 V		1.9	6.8	1.9	7.4	ns	
		V_{CC} = 2.3 V to 2.7 V		1.7	5.3	1.7	5.9	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	4.3	1.7	4.8	ns	
dis	disable time	OE to Y; see Figure 9	[3]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.4	8.8	3.4	9.9	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.2	6.2	2.2	7.1	ns	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.9	6.3	1.9	7.1	ns	
		V_{CC} = 2.3 V to 2.7 V		1.7	4.5	1.7	5.1	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	5.0	1.7	5.6	ns	
C _L = 15 p	F								
pd	propagation delay	A to Y; see Figure 8	<u>[1]</u>						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.3	15.8	3.3	17.5	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.5	9.8	2.5	10.9	ns	
		V _{CC} = 1.65 V to 1.95 V		2.0	7.9	2.0	8.8	ns	
		V_{CC} = 2.3 V to 2.7 V		1.8	6.0	1.8	6.7	ns	
		V_{CC} = 3.0 V to 3.6 V		1.8	5.4	1.8	6.1	ns	
en	enable time	OE to Y; see Figure 9	[2]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	17.6	3.7	19.6	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.5	9.8	2.5	10.7	ns	
		V_{CC} = 1.65 V to 1.95 V		2.1	7.7	2.1	8.5	ns	
		V_{CC} = 2.3 V to 2.7 V		2.0	6.1	2.0	6.8	ns	
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V		1.9	4.9	1.9	5.5	ns	

Table 9. Dynamic characteristics ... continued

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		–40 °C i	to +85 °C	–40 °C to	Unit	
				Min	Max	Min	Max	
dis	disable time	OE to Y; see Figure 9	[3]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	10.3	3.7	11.6	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	7.4	2.5	8.4	ns
		V _{CC} = 1.65 V to 1.95 V		2.1	7.4	2.1	8.9	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.0	5.1	2.0	6.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	6.6	1.9	7.4	ns
C _L = 30 p	F							
t _{pd} propagation delay		A to Y; see Figure 8	[1]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.4	21.6	4.4	24.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	10.3	2.6	11.5	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.5	7.8	2.5	8.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.5	7.5	2.5	8.3	ns
en	enable time	OE to Y; see Figure 9	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	22.8	4.8	25.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.1	12.6	3.1	14.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.8	10.2	2.8	11.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.6	7.8	2.6	8.8	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$		2.6	6.9	2.6	7.7	ns
dis	disable time	OE to Y; see Figure 9	[3]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	14.8	4.8	16.5	ns
		$V_{CC} = 1.4 V \text{ to } 1.6 V$		3.1	10.7	3.1	12.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.8	12.4	2.8	13.8	ns
		V_{CC} = 2.3 V to 2.7 V		2.6	8.6	2.6	9.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.6	10.8	2.6	13.1	ns

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

Low-power buffer/line driver; 3-state

12. Waveforms

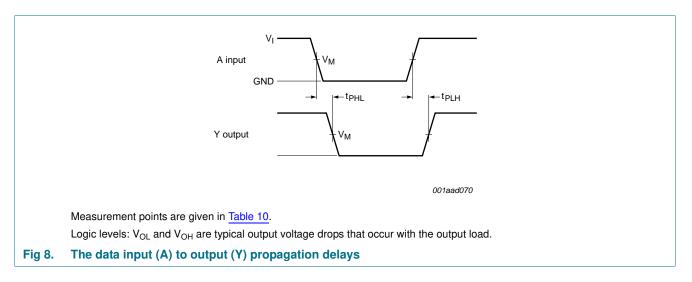
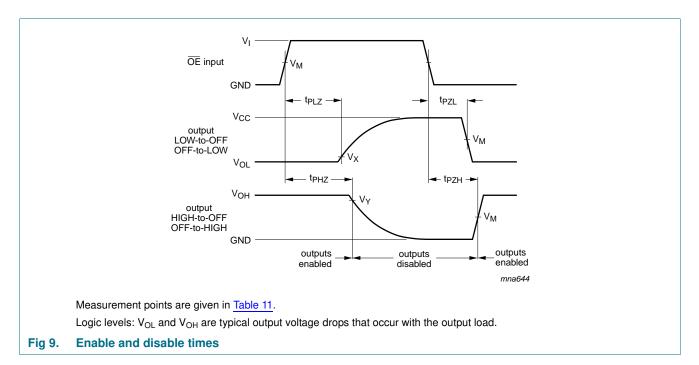


Table 10. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V _M	VI	t _r = t _f		
0.8 V to 3.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	\leq 3.0 ns		



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74AUP1G125

Low-power buffer/line driver; 3-state

Table 11. Measurement points							
Supply voltage	Input	Output					
V _{CC}	V _M	V _M	V _X	V _Y			
0.8 V to 1.6 V	$0.5\times V_{CC}$	$0.5 \times V_{CC}$	V_{OL} + 0.1 V	V _{OH} – 0.1 V			
1.65 V to 2.7 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.15 \ V$	V _{OH} – 0.15 V			
3.0 V to 3.6 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.3 V$	V _{OH} – 0.3 V			

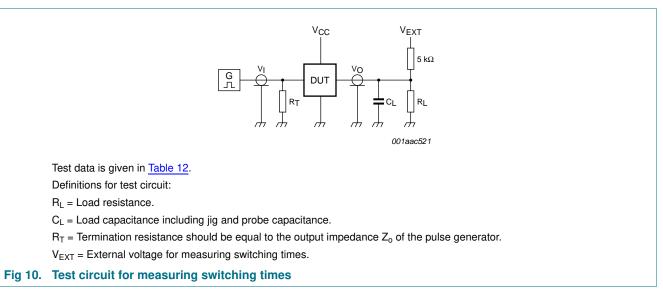


Table 12. Test data

Supply voltage	Load		V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5 \text{ k}\Omega$ or $1 \text{ M}\Omega$	open	GND	$2 \times V_{CC}$	

[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

Low-power buffer/line driver; 3-state

13. Package outline

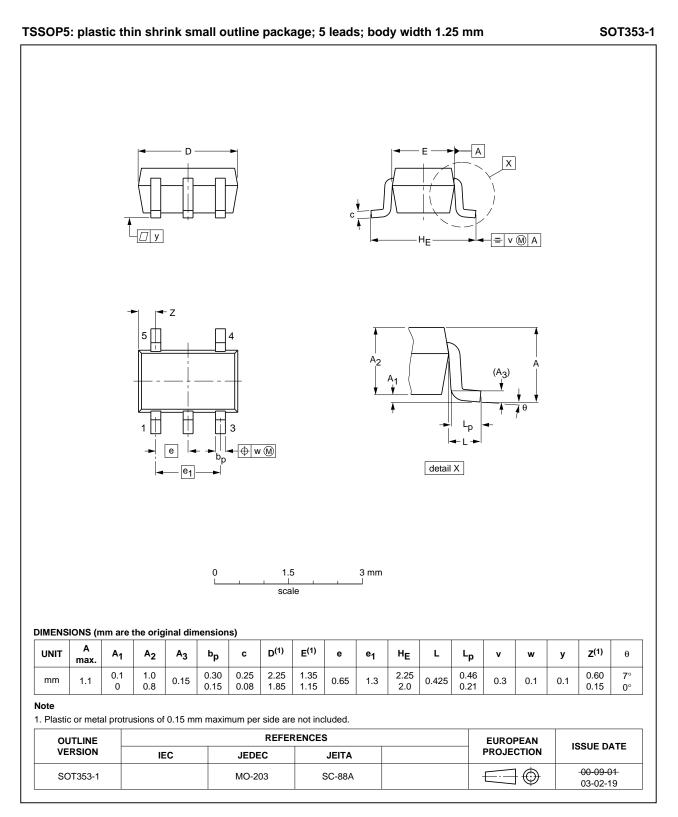


Fig 11. Package outline SOT353-1 (TSSOP5)

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Low-power buffer/line driver; 3-state

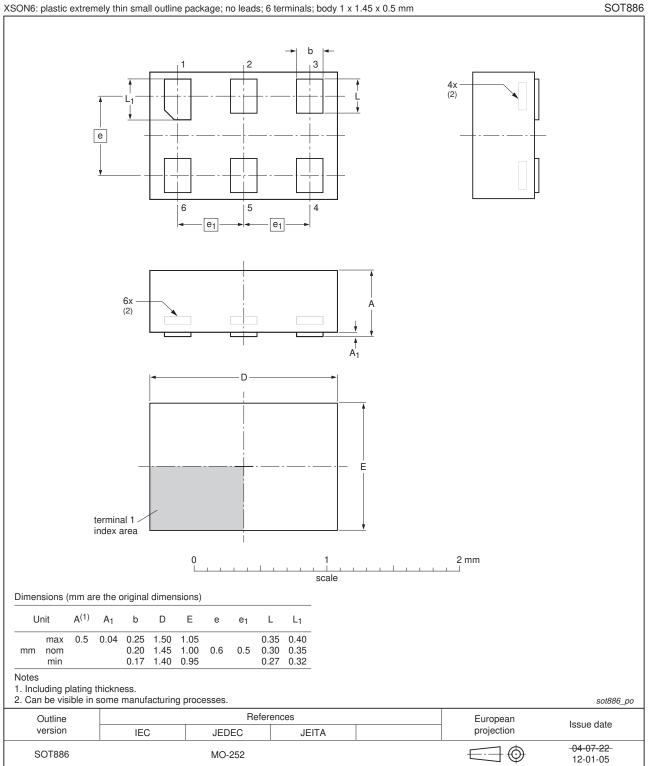


Fig 12. Package outline SOT886 (XSON6)

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Low-power buffer/line driver; 3-state

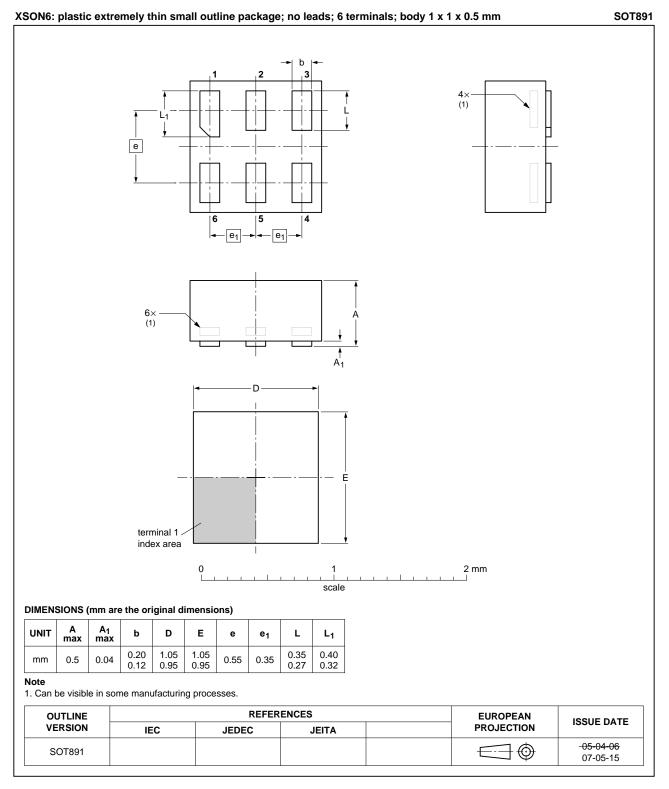
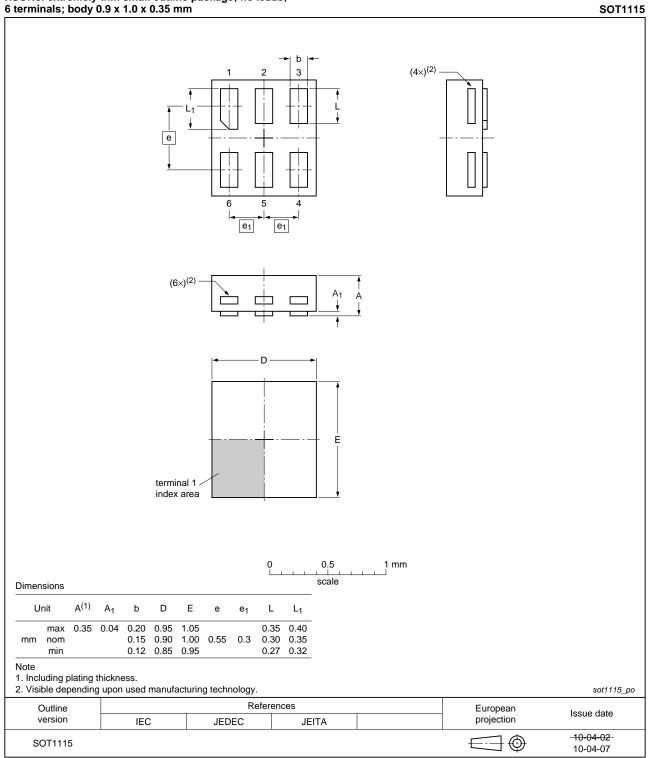


Fig 13. Package outline SOT891 (XSON6)

Low-power buffer/line driver; 3-state



XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

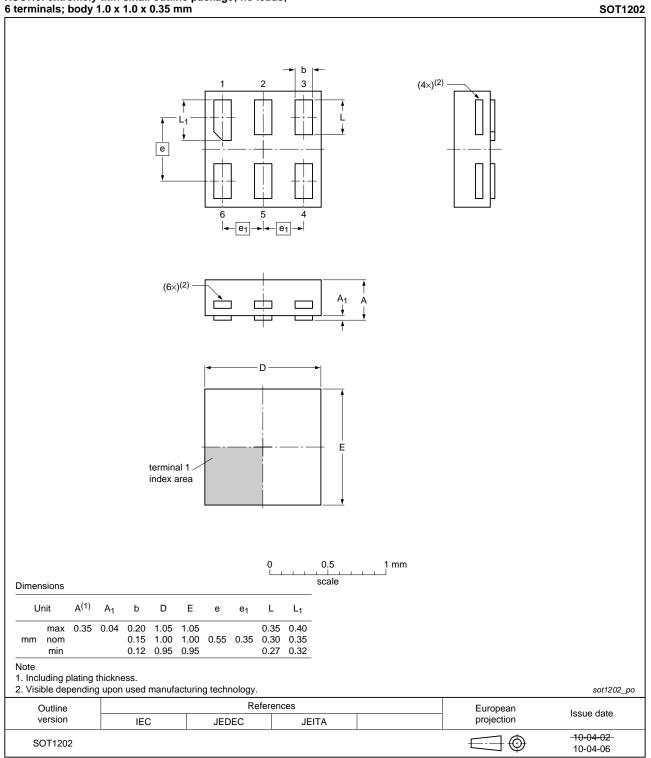
Fig 14. Package outline SOT1115 (XSON6)

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All

Low-power buffer/line driver; 3-state

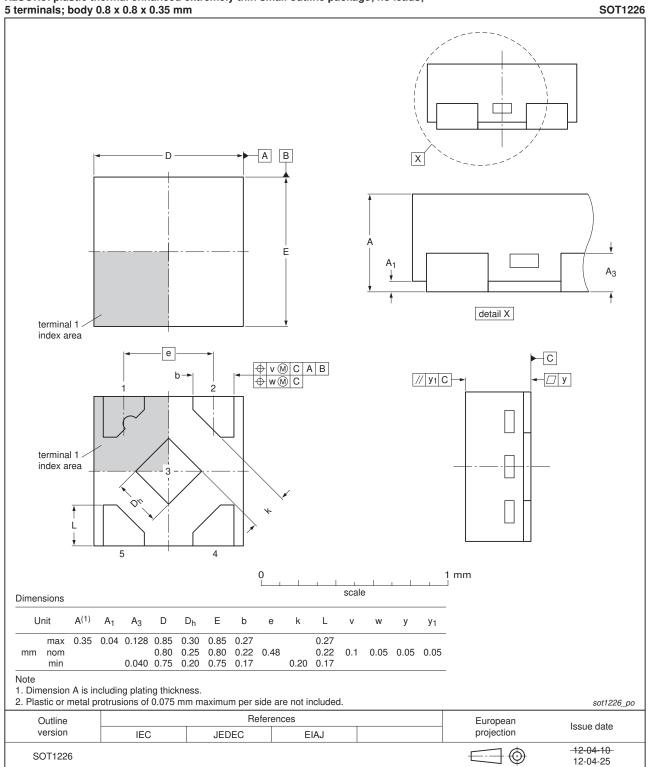


XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)

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Low-power buffer/line driver; 3-state



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;

Fig 16. Package outline SOT1226 (X2SON5)

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Low-power buffer/line driver; 3-state

14. Abbreviations

Table 13. Abb	Table 13. Abbreviations					
Acronym	Description					
CDM	Charged Device Model					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
HBM	Human Body Model					
MM	Machine Model					

15. Revision history

Table 14. Revision history **Document ID Release date** Data sheet status Change notice Supersedes 74AUP1G125 v.6 20120815 Product data sheet 74AUP1G125 v.5 _ Modifications: • Errata in general description corrected 74AUP1G125 v.5 20120731 Product data sheet 74AUP1G125 v.4 -Modifications: Added type number 74AUP1G125GX (SOT1226) • Package outline drawing of SOT886 (Figure 12) modified. 74AUP1G125 v.4 74AUP1G125 v.3 20111129 Product data sheet -74AUP1G125 v.3 20100901 Product data sheet 74AUP1G125 v.2 _ 74AUP1G125 v.2 Product data sheet 74AUP1G125 v.1 20060630 _ 74AUP1G125 v.1 Product data sheet 20050718 --

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Product data sheet

Low-power buffer/line driver; 3-state

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Low-power buffer/line driver; 3-state

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